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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

### Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	12
Program Memory Size	768B (512 x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	25 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SSOP (0.209", 5.30mm Width)
Supplier Device Package	20-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c54c-04i-ss

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



### FIGURE 3-1: PIC16C5X SERIES BLOCK DIAGRAM

#### 3.1 **Clocking Scheme/Instruction** Cycle

The clock input (OSC1/CLKIN pin) is internally divided by four to generate four non-overlapping quadrature clocks, namely Q1, Q2, Q3 and Q4. Internally, the program counter is incremented every Q1 and the instruction is fetched from program memory and latched into the instruction register in Q4. It is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow are shown in Figure 3-2 and Example 3-1.

#### 3.2 Instruction Flow/Pipelining

An Instruction Cycle consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle, while decode and execute takes another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the program counter to change (e.g., GOTO), then two cycles are required to complete the instruction (Example 3-1).

A fetch cycle begins with the program counter (PC) incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the Instruction Register in cycle Q1. This instruction is then decoded and executed during the Q2, Q3 and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).



#### FIGURE 3-2: **CLOCK/INSTRUCTION CYCLE**

#### EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW



is "flushed" from the pipeline, while the new instruction is being fetched and then executed.

# PIC16C5X



# FIGURE 5-4: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): FAST VDD RISE TIME



# FIGURE 5-5: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): SLOW VDD RISE TIME



# 6.2 Data Memory Organization

Data memory is composed of registers, or bytes of RAM. Therefore, data memory for a device is specified by its register file. The register file is divided into two functional groups: Special Function Registers and General Purpose Registers.

The Special Function Registers include the TMR0 register, the Program Counter (PC), the Status Register, the I/O registers (ports) and the File Select Register (FSR). In addition, Special Purpose Registers are used to control the I/O port configuration and prescaler options.

The General Purpose Registers are used for data and control information under command of the instructions.

For the PIC16C54, PIC16CR54, PIC16C56 and PIC16CR56, the register file is composed of 7 Special Function Registers and 25 General Purpose Registers (Figure 6-4).

For the PIC16C55, the register file is composed of 8 Special Function Registers and 24 General Purpose Registers.

For the PIC16C57 and PIC16CR57, the register file is composed of 8 Special Function Registers, 24 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-5).

For the PIC16C58 and PIC16CR58, the register file is composed of 7 Special Function Registers, 25 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-6).

### 6.2.1 GENERAL PURPOSE REGISTER FILE

The register file is accessed either directly or indirectly through the File Select Register (FSR). The FSR Register is described in Section 6.7.

# FIGURE 6-4:

### PIC16C54, PIC16CR54, PIC16C55, PIC16C56, PIC16CR56 REGISTER FILE MAP



GOTO	Unconditional Branch							
Syntax:	[ label ]	GOTO	k					
Operands:	$0 \le k \le 5^{-1}$	11						
Operation:	k → PC<8:0>; STATUS<6:5> → PC<10:9>							
Status Affected:	None							
Encoding:	101k kkkk kkkk							
Description:	GOTO is an unconditional branch. The 9-bit immediate value is loaded into PC bits <8:0>. The upper bits of PC are loaded from STATUS<6:5>. GOTO is a two- cycle instruction.							
Words:	1							
Cycles:	2							
Example:	GOTO THERE							
After Instructi PC =	on address	G (THER	E)					

INCF	Increment f					
Syntax:	[label] INCF f,d					
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d  \in  [0,1] \end{array}$					
Operation:	(f) + 1 $\rightarrow$ (dest)					
Status Affected:	Z					
Encoding:	0010 10df ffff					
Description:	I he contents of register 'f are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.					
Words:	1					
Cycles:	1					
Example:	INCF CNT, 1					
Before Instru CNT Z After Instructi CNT Z	ction = 0xFF = 0 ion = 0x00 = 1					

INCFSZ	Increment f, Skip if 0						
Syntax:	[label] INCFSZ f,d						
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$						
Operation:	(f) + 1 $\rightarrow$ (dest), skip if result = 0						
Status Affected:	None						
Encoding:	0011 11df ffff						
Description:	The contents of register 'f' are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'. If the result is 0, then the next instruction, which is already fetched, is discarded and a NOP is executed instead making it a two- curde instruction						
Words:	1						
Cycles:	1(2)						
Example:	HERE INCFSZ CNT, 1 GOTO LOOP						
	CONTINUE • •						
Before Instru	iction						
PC	= address (HERE)						
After Instruct	ion						
CNT	= CNT + 1;						
if CNT	= 0,						
PC	= address (CONTINUE);						
if CNT	≠ 0, 						
PC	= address (HERE +1)						

NOTES:

# 12.0 ELECTRICAL CHARACTERISTICS - PIC16C54A

# Absolute Maximum Ratings<sup>(†)</sup>

Ambient Temperature under bias	–55°C to +125°C
Storage Temperature	65°C to +150°C
Voltage on VDD with respect to VSS	0V to +7.5V
Voltage on MCLR with respect to Vss <sup>(1)</sup>	0V to +14V
Voltage on all other pins with respect to Vss	0.6V to (VDD + 0.6V)
Total power dissipation <sup>(2)</sup>	800 mW
Max. current out of Vss pin	150 mA
Max. current into VDD pin	100 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, Iik (VI < 0 or VI > VDD)	±20 mA
Output clamp current, IOK (VO < 0 or VO > VDD)	±20 mA
Max. output current sunk by any I/O pin	
Max. output current sourced by any I/O pin	
Max. output current sourced by a single I/O port (PORTA, B or C)	40 mA
Max. output current sunk by a single I/O port (PORTA, B or C)	50 mA

- **Note 1:** Voltage spikes below Vss at the  $\overline{\text{MCLR}}$  pin, inducing currents greater than 80 mA, may cause latch-up. Thus, a series resistor of 50 to 100  $\Omega$  should be used when applying a "low" level to the  $\overline{\text{MCLR}}$  pin rather than pulling this pin directly to Vss.
  - **2:** Power Dissipation is calculated as follows: Pdis = VDD x {IDD  $-\Sigma$  IOH} +  $\Sigma$  {(VDD VOH) x IOH} +  $\Sigma$ (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

# 12.6 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	ppS	
Т		
F	Frequency	T Time
Lowe	ercase letters (pp) and their meanings:	
рр		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer
Uppe	ercase letters and their meanings:	
S		
F	Fall	P Period
н	High	R Rise
Ι	Invalid (Hi-impedance)	V Valid
L	Low	Z Hi-impedance

# FIGURE 12-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54/55/56/57



# 13.1 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

PIC16LCR54A-04 PIC16LCR54A-04I (Commercial, Industrial)			$\begin{array}{l} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$					
PIC16CR54A-04, 10, 20 PIC16CR54A-04I, 10I, 20I (Commercial, Industrial)			Standa Operat	$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$				
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions	
	Vdd	Supply Voltage						
D001		PIC16LCR54A	2.0		6.25	V		
D001 D001A		PIC16CR54A	2.5 4.5		6.25 5.5	V V	RC and XT modes HS mode	
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>		1.5*	_	V	Device in SLEEP mode	
D003	Vpor	VDD Start Voltage to ensure Power-on Reset	_	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	Svdd	VDD Rise Rate to ensure Power-on Reset	0.05*		—	V/ms	See Section 5.1 for details on Power-on Reset	
	IDD	Supply Current <sup>(2)</sup>						
D005		PICLCR54A	—	10	20 70	μA μA	Fosc = 32 kHz, VDD = 2.0V Fosc = 32 kHz, VDD = 6.0V	
D005A		PIC16CR54A		2.0 0.8 90 4.8	3.6 1.8 350 10	mA mA μA	RC <sup>(3)</sup> and XT modes: Fosc = 4.0 MHz, VDD = 6.0V Fosc = 4.0 MHz, VDD = 3.0V Fosc = 200 kHz, VDD = 2.5V HS mode: Fosc = 10 MHz, VDD = 5.5V	
			—	9.0	20	mA	FOSC = 20  MHz,  VDD = 5.5  V	

Legend: Rows with standard voltage device data only are shaded for improved readability.

- \* These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

- 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
  - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
  - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k $\Omega$ .

#### 13.4 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

DC CH	ARACTE	RISTICS	Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended				
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss		0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V	Pin at hi-impedance RC mode only <sup>(3)</sup> XT, HS and LP modes
D040	Vih	Input High Voltage I/O ports I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	0.45 VDD 2.0 0.36 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD VDD VDD	V V V V V V V	For all VDD <sup>(4)</sup> 4.0V < VDD ≤ 5.5V <sup>(4)</sup> VDD > 5.5V RC mode only <sup>(3)</sup> XT, HS and LP modes
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	—	—	V	
D060	lı∟	Input Leakage Current <sup>(1,2)</sup> I/O ports MCLR MCLR T0CKI OSC1	-1.0 -5.0  -3.0 -3.0	0.5 — 0.5 0.5 0.5	+1.0 	μΑ μΑ μΑ μΑ	For VDD $\leq$ 5.5V: VSS $\leq$ VPIN $\leq$ VDD, pin at hi-impedance VPIN = VSS + 0.25V VPIN = VDD VSS $\leq$ VPIN $\leq$ VDD VSS $\leq$ VPIN $\leq$ VDD, XT, HS and LP modes
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, RC mode only
D090	Vон	Output High Voltage <sup>(2)</sup> I/O ports OSC2/CLKOUT	VDD - 0.7 VDD - 0.7			V V	IOH = $-5.4$ mA, VDD = $4.5$ V IOH = $-1.0$ mA, VDD = $4.5$ V, RC mode only

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

**2:** Negative current is defined as coming out of the pin.

3: For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

4: The user may use the better of the two specifications.

# 14.0 DEVICE CHARACTERIZATION - PIC16C54A

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean +  $3\sigma$ ) or (mean -  $3\sigma$ ) respectively, where  $\sigma$  is a standard deviation, over the whole temperature range.





### TABLE 14-1: RC OSCILLATOR FREQUENCIES

Сехт	Rext	Average Fosc @ 5 V, 25°C				
20 pF	3.3K	5 MHz	± 27%			
	5K	3.8 MHz	± 21%			
	10K	2.2 MHz	± 21%			
	100K	262 kHz	± 31%			
100 pF	3.3K	1.6 MHz	± 13%			
	5K	1.2 MHz	± 13%			
	10K	684 kHz	± 18%			
	100K	71 kHz	± 25%			
300 pF	3.3K	660 kHz	± 10%			
	5.0K	484 kHz	± 14%			
	10K	267 kHz	± 15%			
	100K	29 kHz	± 19%			

The frequencies are measured on DIP packages.

The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is  $\pm 3$  standard deviations from the average value for VDD = 5V.

# 15.1 DC Characteristics: PIC16C54A-04, 10, 20 (Commercial) PIC16C54A-04I, 10I, 20I (Industrial) PIC16LC54A-04 (Commercial) PIC16LC54A-04I (Industrial)

PIC16LC54A-04 PIC16LC54A-04I (Commercial, Industrial)				$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$					
PIC16C54A-04, 10, 20 PIC16C54A-04I, 10I, 20I (Commercial, Industrial)			<b>Stand</b> Opera	$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$					
Param No. Symbol Characteristic/Device				Тур†	Max	Units	Conditions		
	Vdd	Supply Voltage							
D001		PIC16LC54A	3.0 2.5	_	6.25 6.25	V V	XT and RC modes LP mode		
D001A		PIC16C54A	3.0 4.5	_	6.25 5.5	V V	RC, XT and LP modes HS mode		
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>	—	1.5*	—	V	Device in SLEEP mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset		
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	—	-	V/ms	See Section 5.1 for details on Power-on Reset		
	IDD	Supply Current <sup>(2)</sup>							
D005		PIC16LC5X	_	0.5	2.5	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC <sup>(3)</sup> and XT modes		
				11	27	μΑ	Fosc = 32 kHz, VDD = 2.5V, WDT disabled, LP mode, Commercial		
			_	11	35	μΑ	Fosc = 32 kHz, VDD = 2.5V, WDT disabled, LP mode, Industrial		
D005A		PIC16C5X	—	1.8	2.4	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC <sup>(3)</sup> and XT modes		
			—	2.4	8.0	mA	FOSC = 10 MHz, VDD = 5.5V, HS mode		
			—	4.5	16	mA	FOSC = 20  MHz,  VDD = 5.5V, HS mode		
				14	29	μA	HOSC = 32 kHz, VDD = 3.0V,		
			-	17	37	μΑ	Fosc = 32 kHz, VDD = 3.0V, WDT disabled, LP mode, Industrial		

Legend: Rows with standard voltage device data only are shaded for improved readability.

These parameters are characterized but not tested.

- † Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k $\Omega$ .

# 15.5 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	pS	
Т		
F	Frequency	T Time
Lowe	ercase letters (pp) and their meanings:	
рр		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer
Uppe	ercase letters and their meanings:	
S		
F	Fall	P Period
н	High	R Rise
I	Invalid (Hi-impedance)	V Valid
L	Low	Z Hi-impedance

# FIGURE 15-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54A





### FIGURE 15-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C54A

### TABLE 15-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C54A

$\begin{tabular}{ c c c c c } \hline Standard Operating Conditions (unless otherwise specified) \\ Operating Temperature & 0°C \leq TA \leq +70°C \ for \ commercial \\ -40°C \leq TA \leq +85°C \ for \ industrial \\ -20°C \leq TA \leq +85°C \ for \ industrial - PIC16LV54A-02I \\ -40°C \leq TA \leq +125°C \ for \ extended \\ \hline \end{tabular}$						e <b>d)</b> al - PIC16LV54A-02I d	
Param No.	Symbol	Characteristic Min Typ† Max Units Conditions					
30	TmcL	MCLR Pulse Width (low)	100* 1			ns μs	VDD = 5.0V VDD = 5.0V (PIC16LV54A only)
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
32	Tdrt	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low			100* 1μs	ns —	(PIC16LV54A only)

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

# PIC16C5X

# FIGURE 16-5: TYPICAL IPD vs. VDD, WATCHDOG DISABLED (25°C)







### 17.3 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial, Extended) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial, Extended) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

DC CHARACTERISTICS			$ \begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \\ \end{array} $					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O Ports I/O Ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss Vss Vss		0.8 V 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V V	4.5V <v<sub>DD ≤ 5.5V Otherwise RC mode only<sup>(3)</sup> XT, HS and LP modes</v<sub>	
D040	Vih	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	2.0 0.25 Vdd+0.8 0.85 Vdd 0.85 Vdd 0.85 Vdd 0.85 Vdd 0.7 Vdd	 	Vdd Vdd Vdd Vdd Vdd Vdd Vdd	V V V V V	4.5V < V <sub>DD</sub> ≤ 5.5V Otherwise RC mode only <sup>(3)</sup> XT, HS and LP modes	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	—	_	V		
D060	lı∟	Input Leakage Current <sup>(1,2)</sup> I/O ports	-1.0	0.5	+1.0	μA	For VDD $\leq$ 5.5V: VSS $\leq$ VPIN $\leq$ VDD, pin at hi-impedance	
		MCLR MCLR T0CKI OSC1	-5.0 -3.0 -3.0	— 0.5 0.5 0.5	+5.0 +3.0 +3.0 —	μΑ μΑ μΑ μΑ	$VPIN = VSS +0.25V$ $VPIN = VDD$ $VSS \le VPIN \le VDD$ $VSS \le VPIN \le VDD,$ $XT, HS and LP modes$	
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_	0.6 0.6	V V	IOL = 8.7  mA,  VDD = 4.5 V IOL = 1.6  mA,  VDD = 4.5 V, RC mode only	
D090	Vон	Output High Voltage <sup>(2)</sup> I/O ports OSC2/CLKOUT	Vdd - 0.7 Vdd - 0.7			V V	IOH = -5.4  mA,  VDD = 4.5 V IOH = -1.0  mA,  VDD = 4.5 V, RC mode only	

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

- Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.
  - **2:** Negative current is defined as coming out of the pin.
  - 3: For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

## 17.5 Timing Diagrams and Specifications



### FIGURE 17-6: EXTERNAL CLOCK TIMING - PIC16C5X, PIC16CR5X

### TABLE 17-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X, PIC16CR5X

AC Characteristics										
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions			
	Fosc	External CLKIN Frequency <sup>(1)</sup>	DC		4.0	MHz	XT OSC mode			
			DC	—	4.0	MHz	HS osc mode (04)			
			DC	—	20	MHz	HS osc mode (20)			
			DC	_	200	kHz	LP OSC mode			
		Oscillator Frequency <sup>(1)</sup>	DC	—	4.0	MHz	RC osc mode			
			0.45	—	4.0	MHz	XT OSC mode			
			4.0	—	4.0	MHz	HS osc mode (04)			
			4.0	—	20	MHz	HS osc mode (20)			
			5.0	_	200	kHz	LP OSC mode			
1	Tosc	External CLKIN Period <sup>(1)</sup>	250		—	ns	XT OSC mode			
			250	—	—	ns	HS osc mode (04)			
			50	—	—	ns	HS osc mode (20)			
			5.0		—	μS	LP OSC mode			
		Oscillator Period <sup>(1)</sup>	250		—	ns	RC osc mode			
			250	—	2,200	ns	XT osc mode			
			250	—	250	ns	HS osc mode (04)			
			50	—	250	ns	HS osc mode (20)			
			5.0	—	200	μS	LP OSC mode			

\* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

**Note 1:** All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

**2:** Instruction cycle period (TCY) equals four times the input oscillator time base period.



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IABLE 19-2:	CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C5X-40

AC Characteristics		Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial								
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units				
10	TosH2ckL	OSC1↑ to CLKOUT↓ <sup>(1,2)</sup>		15	30**	ns				
11	TosH2ckH	OSC1↑ to CLKOUT↑ <sup>(1,2)</sup>	—	15	30**	ns				
12	TckR	CLKOUT rise time <sup>(1,2)</sup>	—	5.0	15**	ns				
13	TckF	CLKOUT fall time <sup>(1,2)</sup>	—	5.0	15**	ns				
14	TckL2ioV	CLKOUT↓ to Port out valid <sup>(1,2)</sup>	—		40**	ns				
15	TioV2ckH	Port in valid before CLKOUT <sup>(1,2)</sup>	0.25 TCY+30*	—	—	ns				
16	TckH2iol	Port in hold after CLKOUT <sup>(1,2)</sup>	0*	—	—	ns				
17	TosH2ioV	OSC1 <sup>↑</sup> (Q1 cycle) to Port out valid <sup>(2)</sup>	—	—	100	ns				
18	TosH2iol	OSC1↑ (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	—	ns				
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns				
20	TioR	Port output rise time <sup>(2)</sup>	—	10	25**	ns				
21	TioF	Port output fall time <sup>(2)</sup>		10	25**	ns				

\* These parameters are characterized but not tested.

- \*\* These parameters are design targets and are not tested. No characterization data available at this time.
- † Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Refer to Figure 19-2 for load conditions.

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### 28-Lead Plastic Shrink Small Outline (SS) - 209 mil, 5.30 mm (SSOP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging









	INCHES			MILLIMETERS*			
Dimension	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		28			28	
Pitch	р		.026			0.65	
Overall Height	А	.068	.073	.078	1.73	1.85	1.98
Molded Package Thickness	A2	.064	.068	.072	1.63	1.73	1.83
Standoff §	A1	.002	.006	.010	0.05	0.15	0.25
Overall Width	E	.299	.309	.319	7.59	7.85	8.10
Molded Package Width	E1	.201	.207	.212	5.11	5.25	5.38
Overall Length	D	.396	.402	.407	10.06	10.20	10.34
Foot Length	L	.022	.030	.037	0.56	0.75	0.94
Lead Thickness	С	.004	.007	.010	0.10	0.18	0.25
Foot Angle	¢	0	4	8	0.00	101.60	203.20
Lead Width	В	.010	.013	.015	0.25	0.32	0.38
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

\* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-150 Drawing No. C04-073

# 28-Lead Ceramic Dual In-line with Window (JW) - 600 mil (CERDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	INCHES*			MILLIMETERS			
Dimension	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		28			28	
Pitch	р		.100			2.54	
Top to Seating Plane	А	.195	.210	.225	4.95	5.33	5.72
Ceramic Package Height	A2	.155	.160	.165	3.94	4.06	4.19
Standoff	A1	.015	.038	.060	0.38	0.95	1.52
Shoulder to Shoulder Width	Е	.595	.600	.625	15.11	15.24	15.88
Ceramic Pkg. Width	E1	.514	.520	.526	13.06	13.21	13.36
Overall Length	D	1.430	1.460	1.490	36.32	37.08	37.85
Tip to Seating Plane	L	.125	.138	.150	3.18	3.49	3.81
Lead Thickness	С	.008	.010	.012	0.20	0.25	0.30
Upper Lead Width	B1	.050	.058	.065	1.27	1.46	1.65
Lower Lead Width	В	.016	.020	.023	0.41	0.51	0.58
Overall Row Spacing §	eB	.610	.660	.710	15.49	16.76	18.03
Window Diameter	W	.270	.280	.290	6.86	7.11	7.37

Sontolling Parameter
 Significant Characteristic
 JEDEC Equivalent: MO-103
 Drawing No. C04-013